## NSN 5961-01-187-0543



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-187-0543 **Inclosure Material:** Metal **Overall Length:** 0.935 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-60 **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 55.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, collector-to-emitter, base open and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 400.00 milliamperes source cutoff current and 400.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 4.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 uninsulated wire lead and 1 threaded stud Shelf Life:

Demilitarization:

**Unit Of Measure:** 

No

N/a

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